

MAS836 – Sensor Technologies for Interactive Environments



## *Lecture 11 – Temperature and Acoustic Sensing*



# Temperature Measurements

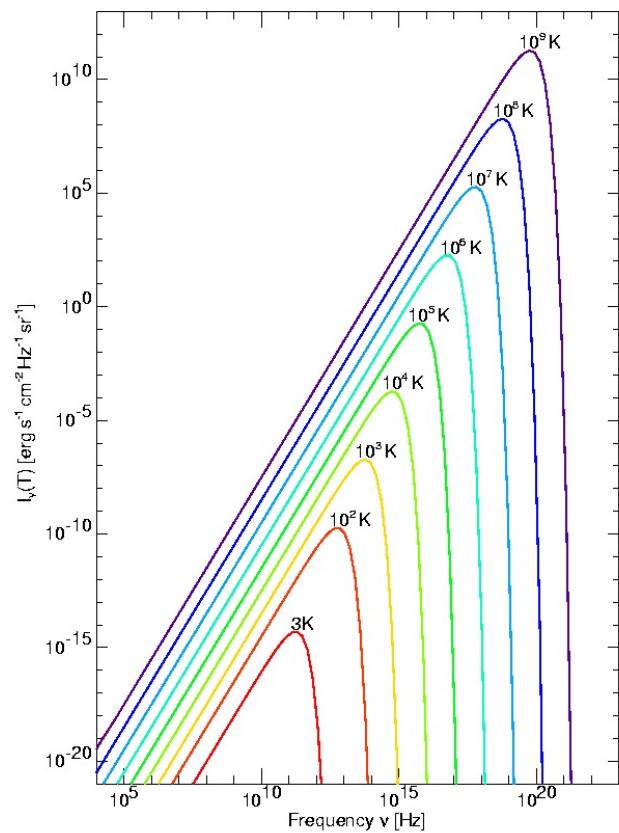
- Read Fraden, Ch. 11, Ch. 16, Ch. 13 (II Ed.)
- Most materials exhibit a temperature effect
  - Mechanical or electrical or radiative
- Contact and noncontact (remote) temperature measurements

# Blackbody Radiation



Spectrum

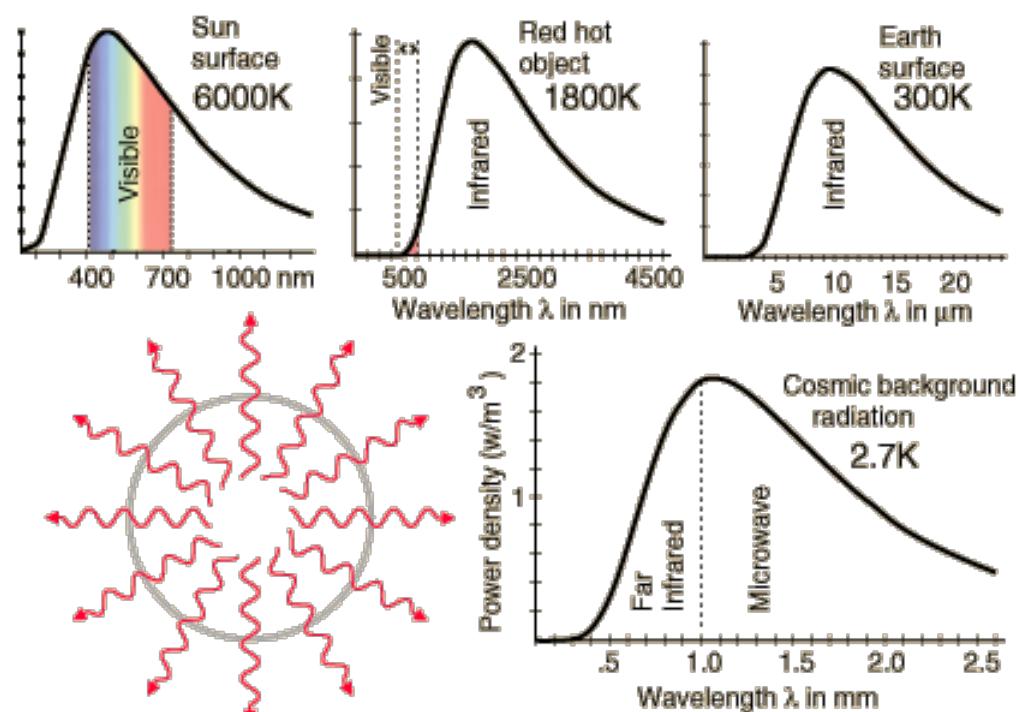
3-8



IAAT

Blackbody Radiation: Properties

1



From Planck – sum of oscillators

# Pyroelectricity

Some piezoelectric materials are pyroelectric  
Heat flux deforms crystal & creates charge

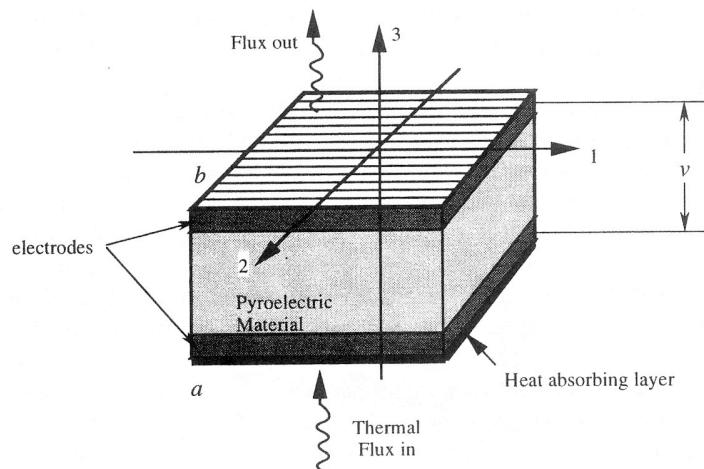


FIGURE 3.26. Pyroelectric sensor has two electrodes at the opposite sides of the crystal. Thermal radiation is applied along axis 3.

$$P_Q = \frac{dP_s}{dT} \quad \text{Pyroelectric charge coefficient,}$$

$$P_V = \frac{dE}{dT} \quad \text{Pyroelectric voltage coefficient,}$$

$$\Delta V = P_Q \frac{A}{C_e} \Delta T = P_Q \frac{\epsilon_r \cdot \epsilon_0}{h} \Delta T.$$

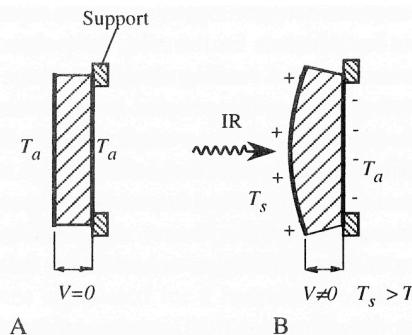
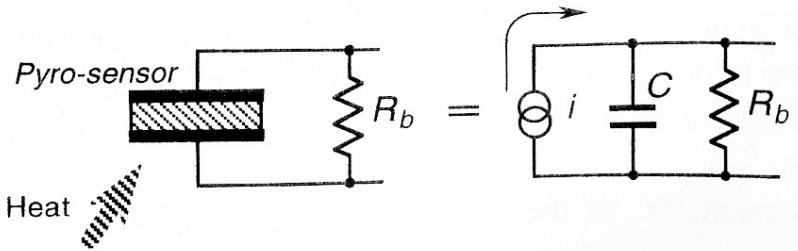


FIGURE 6.14. A simplified model of a pyroelectric effect as a secondary effect of piezoelectricity. Initially, the element has a uniform temperature (A); upon exposure to thermal radiation, its front side expands, causing a stress induced charge (B).

## Differential Sensors

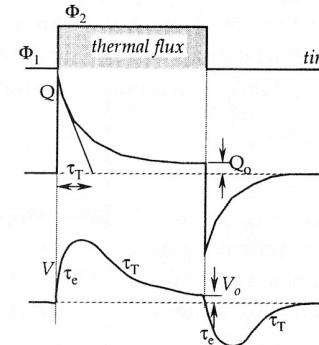


FIGURE 3.29. Response of a pyroelectric sensor to a thermal step function. The magnitudes of charge  $Q_o$  and voltage  $V_o$  are exaggerated for clarity.

$$i = i_0 e^{-t/\tau_T}$$

$$\tau_T = CR = cAhR$$

C = Thermal Capacitance  
=  $cV$  (heat capacity \* volume)

R = Thermal Resistance  
= heat loss to environment

9 um PVDF, Lithium Tantalate, etc.  
PVDF is pyroelectric in 7-20 um (0-50° C)

# Pyroelectric Motion Detectors

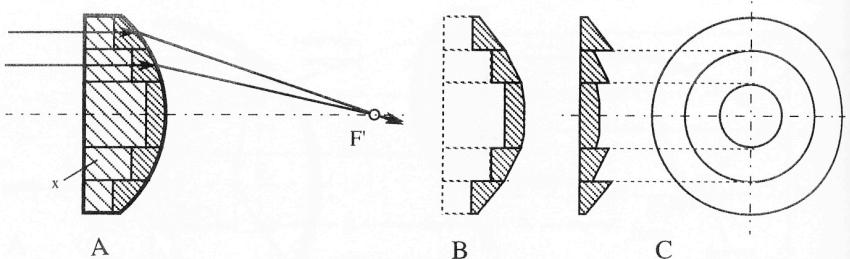
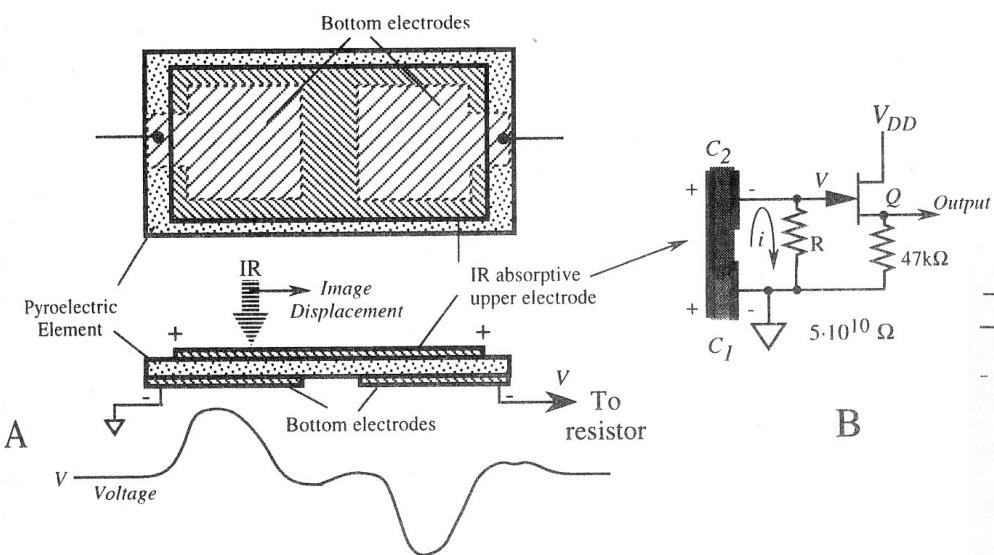
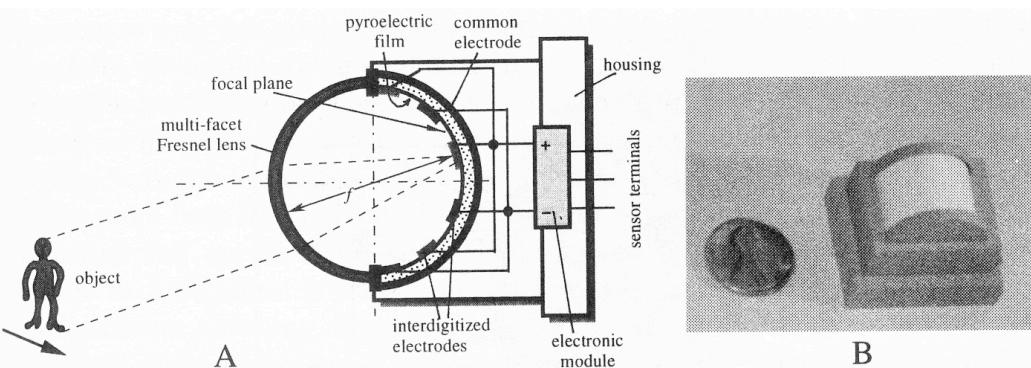


FIGURE 3.61. Concept of a Fresnel lens.

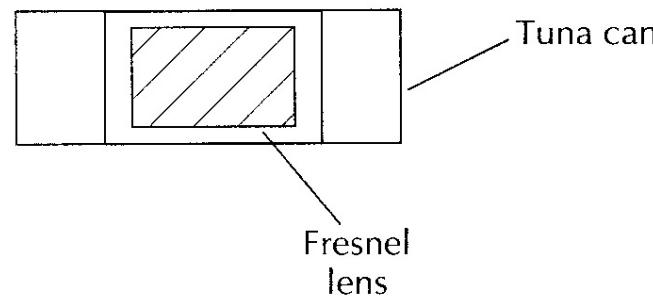
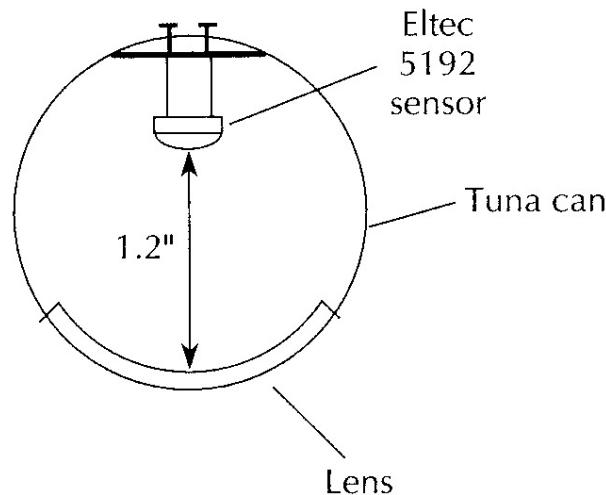
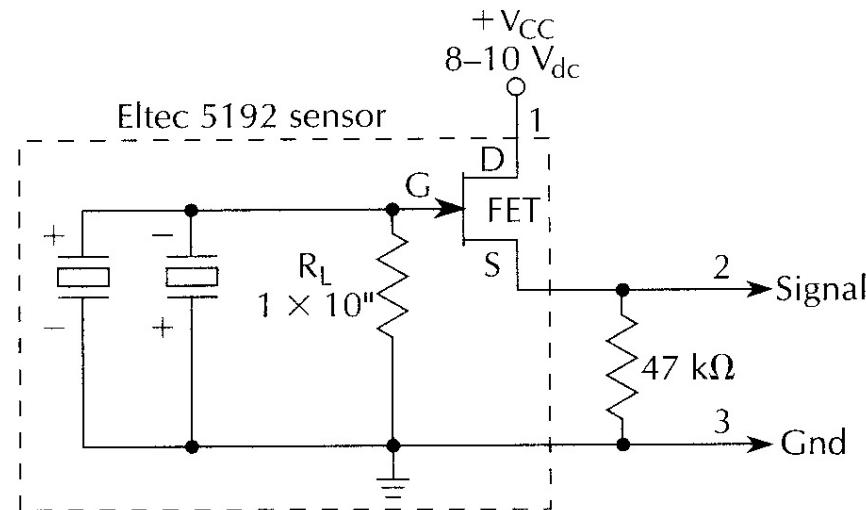
**FIGURE 6.15.** Dual pyroelectric sensor. A sensing element with a front (upper) electrode and two bottom electrodes deposited on a common crystalline substrate (A). A moving thermal image travels from left part of the sensor to the right generating an alternate voltage across bias resistor,  $R$  (B).

Fresnel lens collapses lens to planar structure  
 - Index of refraction steps discretized  
 Lens is thinner - less absorption of deep IR  
 - Polystyrene, etc.



**FIGURE 6.16.** Far infrared motion detector with a curved Fresnel lens and a pyroelectric PVDF film. A: Internal structure of the sensor; B: external appearance of the sensor.

# Pyroelectric Motion Detectors



Another is:  
442-3 IR-EYE  
or:  
PYD 1998



**Fig. 8-10** Pyroelectric sensor tuna-can mount. (from Petruzelis)

# PIR Lens Configurations

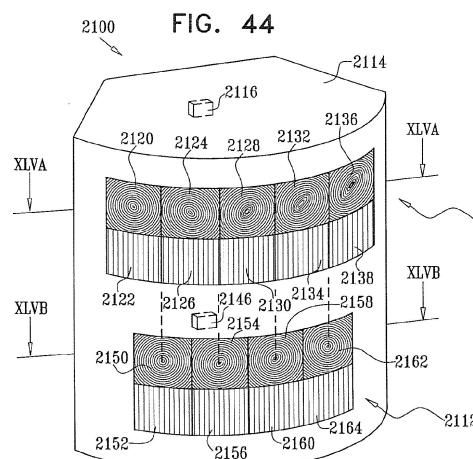


FIG. 44

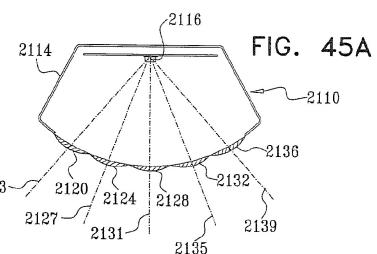
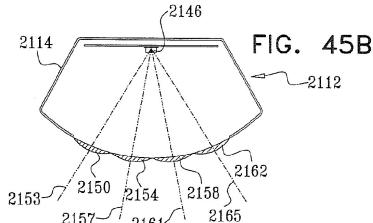


FIG. 45A



45B

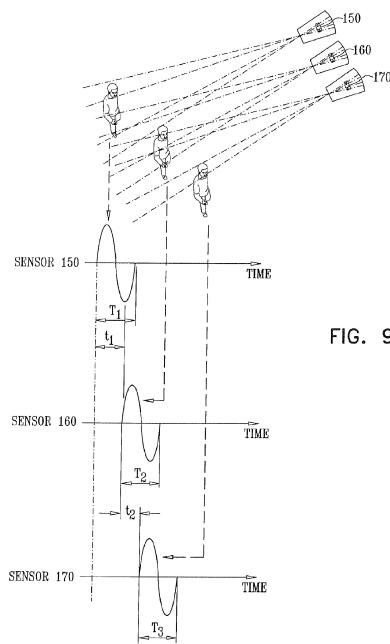


FIG. 9A

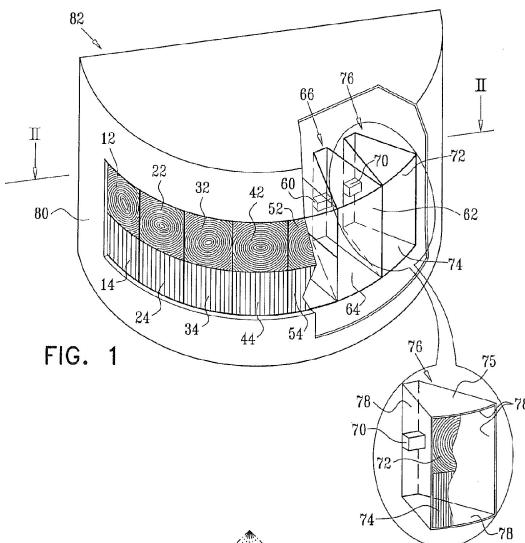


FIG. 1

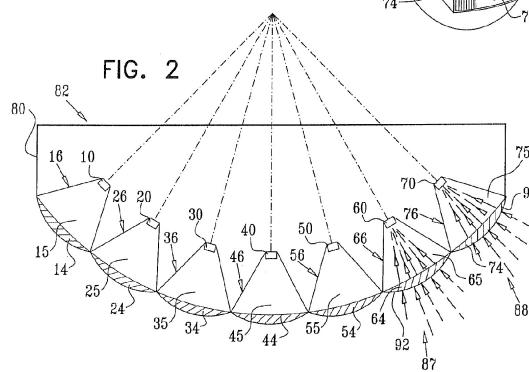


FIG. 2

Many ‘sweeps’ across adjacent views

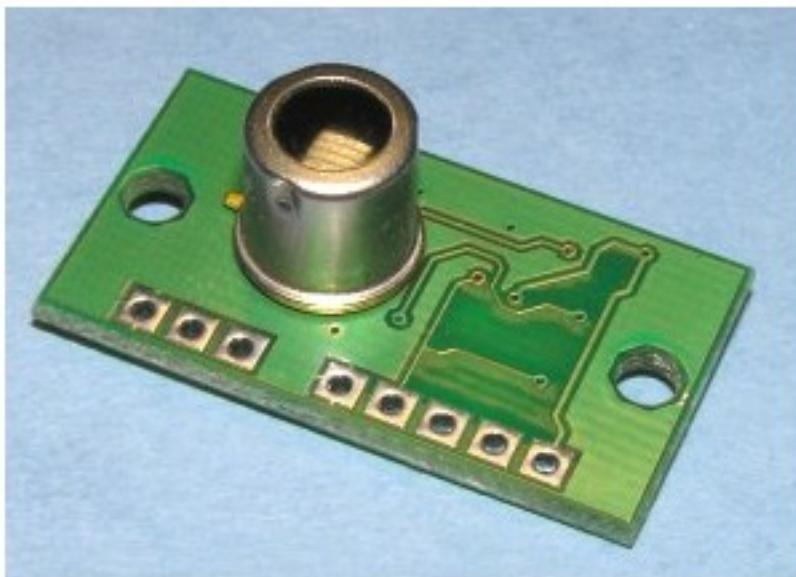
*US Patent Application No.: US 2007/0029486A1 Zhevelev et al.*

# AFIR Detectors

- Project heat source through thermal lens
- Measure current required to keep temperature of heat source stable
- Current will vary with radiation absorption of objects in lens field-of-view
- Impervious to extraneous heat sources...

# Pyroelectric Line Array

TPA81 - 8x1 Thermopile array



Voltage - 5v only required

Current - 5mA Typ. excluding servo

Temperature Range - 4°C - 100°C

Accuracy (Full FOV) - +/-2°C +/-2% from 10°C to 100°C,

Accuracy (Full FOV) - +/-3°C from 4°C to 10°C

Field of View - 41° x 6° (8 pixels of approx. 5° x 6°)

Outputs - 1 ambient + 8 pixel temperatures

Communication - I2C Interface

Servo - Controls servo in 32 steps to 180° rotation

Small Size - 31mm x 18mm

From:

<http://www.robot-electronics.co.uk>

## Full Technical Data

Detects a candle flame at a range 2 metres (6ft) and is unaffected by ambient light!

Detect Human Body heat!

Servo control for image construction!

## 8 Pixel Thermal Array Sensor

# Pyroelectric Videcons

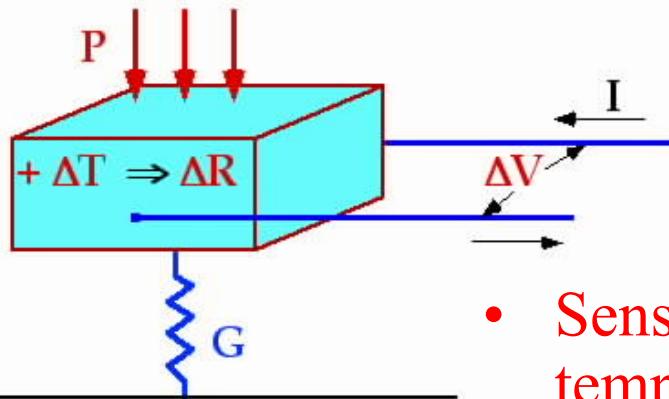
- Thermal imaging cameras
  - Arrays of pyroelectric elements
  - Generally shuttered (look at temp. reference, then look at scene) and/or periodically discharged.
  - Previously most were cooled (w. Peltier devices) to avoid background
  - Limit heat capacity, heat storage in components to increase bandwidth and sensitivity

# Bolometer Arrays

## Bolometer

(From Greek: *bole'* - beam and *metreo* - measuring)

- instrument for measuring radiation by means of the rise in temperature of a metal strip
- invented by the American scientist Samuel Langley in 1880.
- The most sensitive detector of mm and IR radiation.



thermal reservoir  $T_0$   
(substrate)

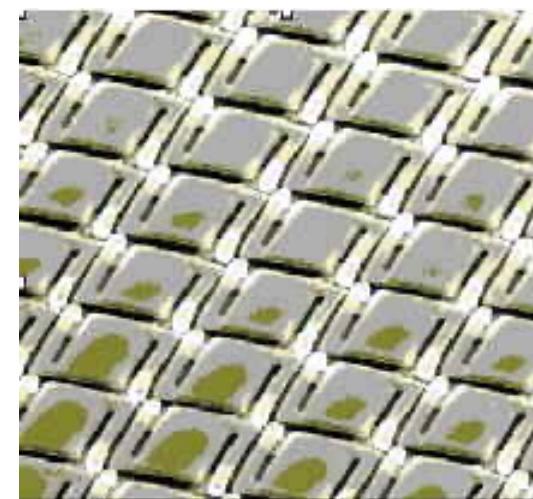
### Types of bolometers:

1880 - metal strip

1961 - semiconductor

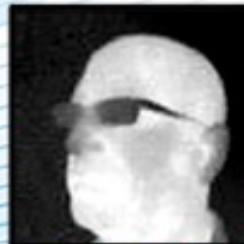
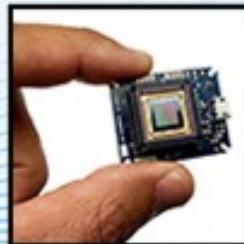
1977 - superconductor

1993 - metal strip



- Sensing elements change resistance with temperature (phase transition)
- Incident radiation (thermal, RF) heats elements
  - Read out via bridge
- Uncooled devices are now made
- Imaging arrays not too expensive (e.g., \$3K)

Infrared camera core easily integrated  
into OEM products



# Smaller, Hotter, Cheaper!

## The ATOM™ 80 Uncooled Microbolometer Core

First in a new generation of low cost infrared cameras.

NEW!

Ideal for OEMs that seek to create new sensing systems that take advantage of low cost infrared imaging capabilities. The ATOM 80 thermal imaging core detects the heat emitted by humans or warm objects. For advanced thermal detection applications such as: building automation and energy management (HVAC and lighting), access control and security, advanced presence detection (e.g. people counting), transportation, thermography.

[Tell me more!](#)

[Let's talk technical](#)

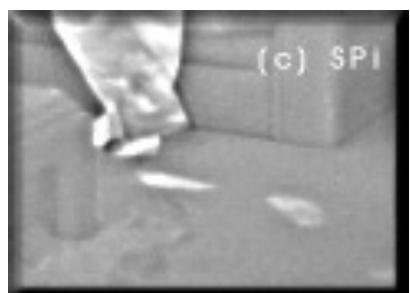
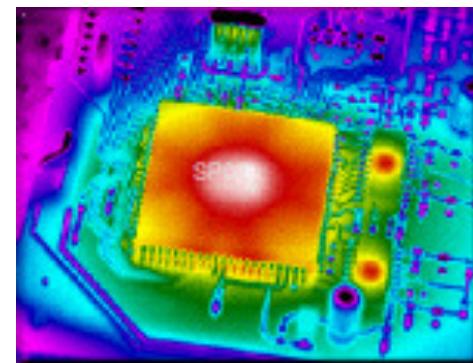
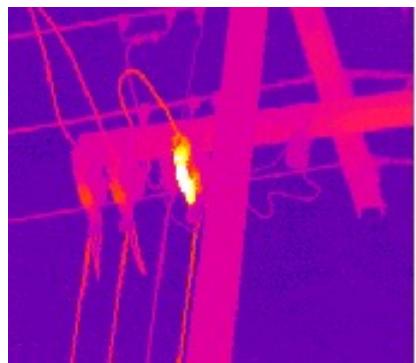
[I want pricing information](#)

Actual ATOM 80 thermal images!

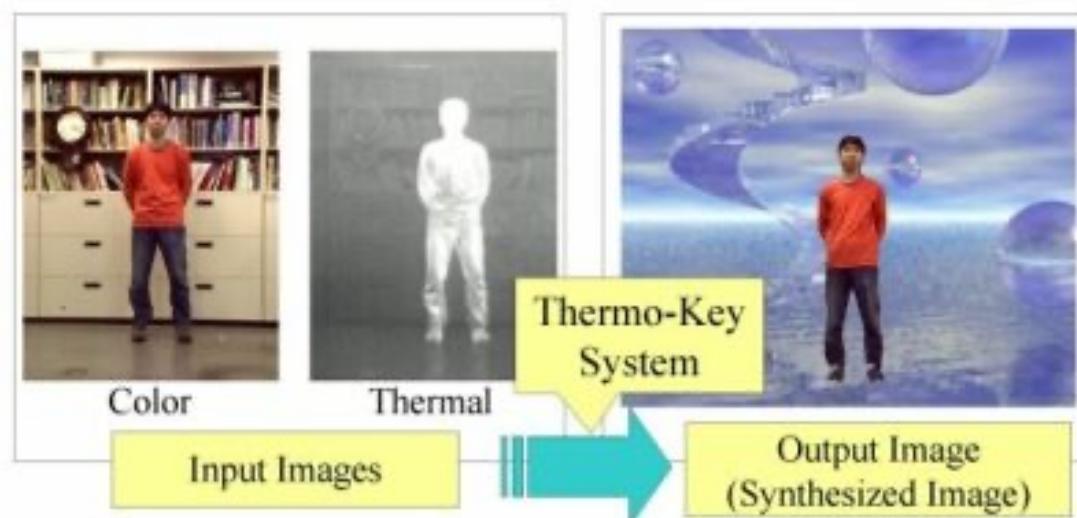


See also FLIR, etc.

# Thermal Imaging



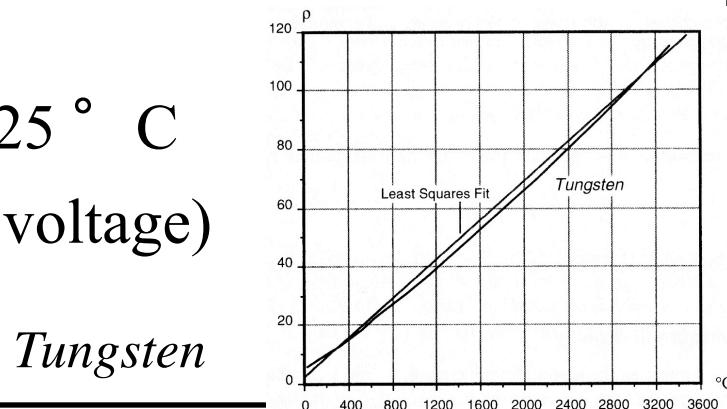
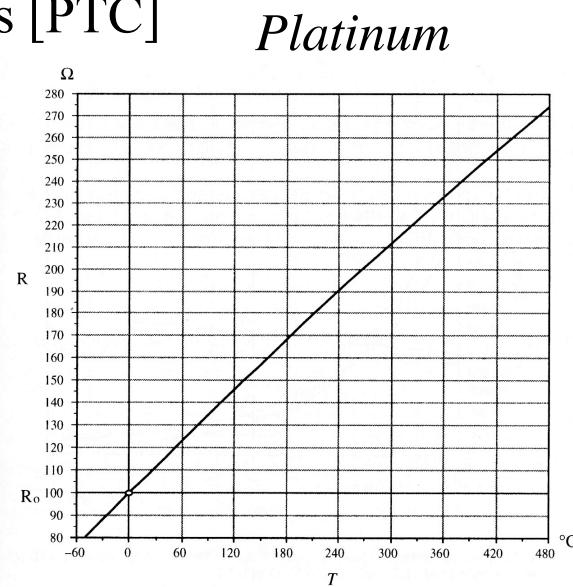
[www.x20.org/thermal/](http://www.x20.org/thermal/)



Thermo-Key (U. Tokyo)

# Thermo Resistive Sensors

- Resistance Temperature Detectors (RTD's)
  - Measure resistance of metal wire
    - Metals have Positive temperature coefficients [PTC]
    - Effective over extremes of temperature
  - Platinum most common
    - Nicely linear from -200° C - 630° C
    - $R = R_0(1.0036 + 36.79 \cdot 10^{-4} T)$
  - Tungsten is used over 600° C
- Linearized around reference point
- Wirewound devices
  - Tolerances within  $\pm 10 \text{ m}\Omega \rightarrow \pm 0.025^\circ \text{ C}$
  - Read with constant current (measure voltage)



# Silicon RTD's

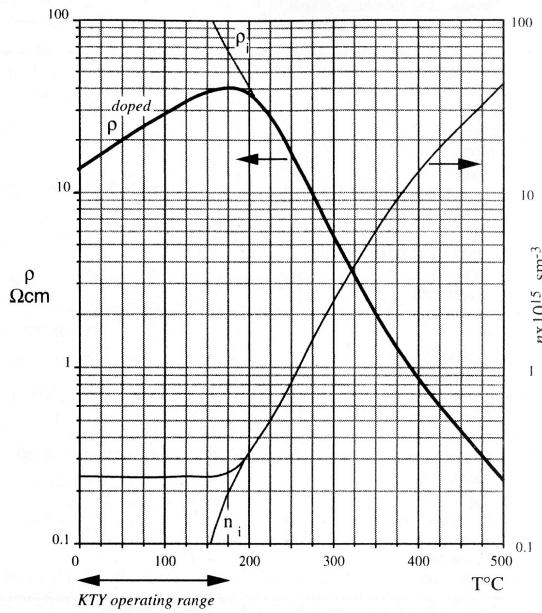


FIGURE 16.3. Resistivity and number of free charge carriers for  $n$ -doped silicon.

- Much cheaper, more sensitive than Pt
- Bulk silicon has a negative TC (NTC)
  - Thermal runaway possible with home heating apps
    - Silicon gets hotter, lower resistance, more current, hotter, lower resistance...
  - Can be doped to have PTC in selected region (e.g.,  $<200^\circ \text{ C}$ )
    - This can produce a silicon RTD that works between  $-50^\circ \text{ C}$  to  $150^\circ \text{ C}$  that's stable and delivers 0.7% per  $^\circ \text{ C}$
  - Philips KTY Sensors

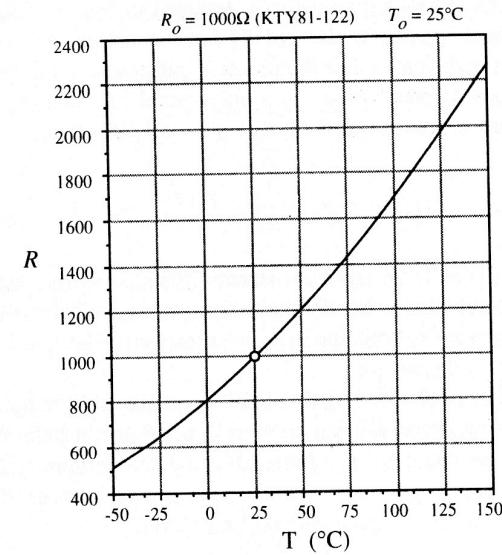


FIGURE 16.4. Transfer function of a KTY silicon temperature sensor.

# Thermistors

$$R = R_o e^{-\beta(1/T - 1/T_o)}$$

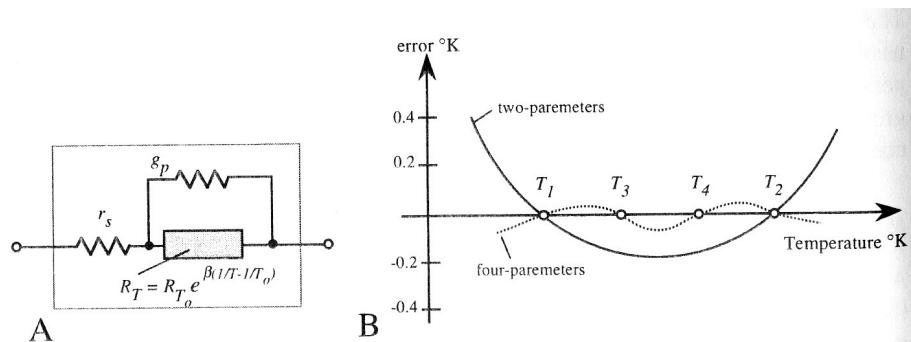


FIGURE 16.5. An equivalent circuit diagram of NTC thermistor (A) and error of a thermistor sensor resulted from use of four- and two-parameter approximations (B).

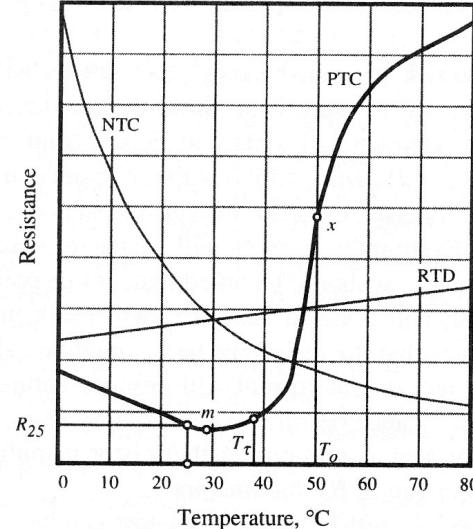


FIGURE 16.10. Transfer functions of PTC and NTC thermistors as compared with RTD.

- Thermistors are temperature-sensitive resistors
  - Compensate thermal effects in analog circuits...
- Metal Oxide Thermistors have NTC
- Much more sensitive than RTD
  - Goes from -8% to -2% per ° C
  - NTC worse for self-heating, runaway problems
    - Depends on airflow...
- Can make PTC thermistors
  - Polycrystalline ceramic (Barium or Strontium Titanate)
  - PTC sensitivity can get to 200% per ° C
    - Narrower range...

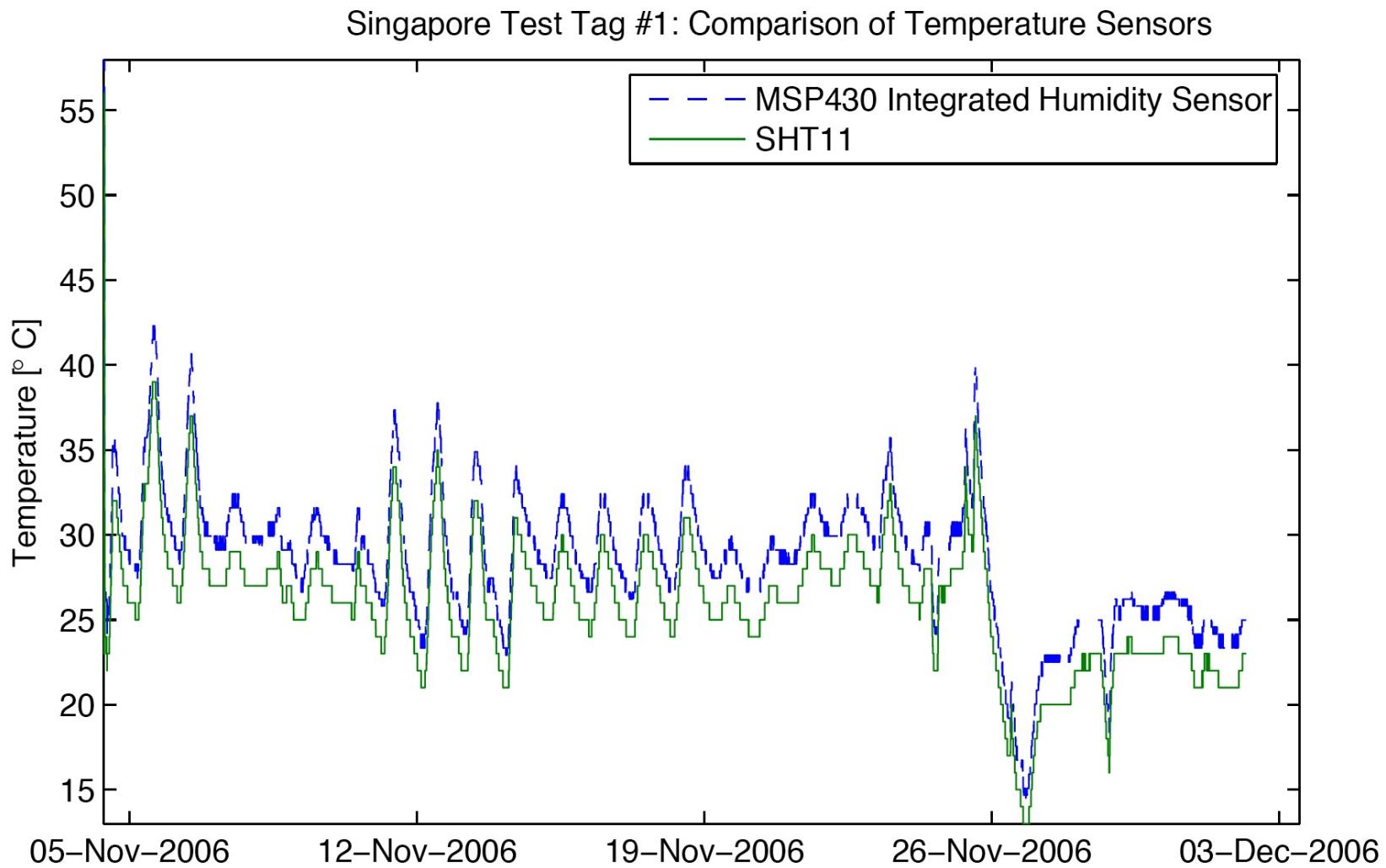
*Thermistors can age (chip packaged  
can degrade at +1% per yr, glass  
beads much slower)*

# Semiconductor Junctions

$$I_c = I_o e^{\frac{qV_{BE}}{2kT}}$$

- Every transistor is a temperature sensor
- Most thermometer IC's exploit this
- Many packages available
  - LM35Z from National
  - AD592 from Analog
  - Dallas Digital TMP series
- Often integrated into microcomputers too
  - Cygnal (Silicon Labs) devices, AD Microconverters

# Internal vs. External Sensors



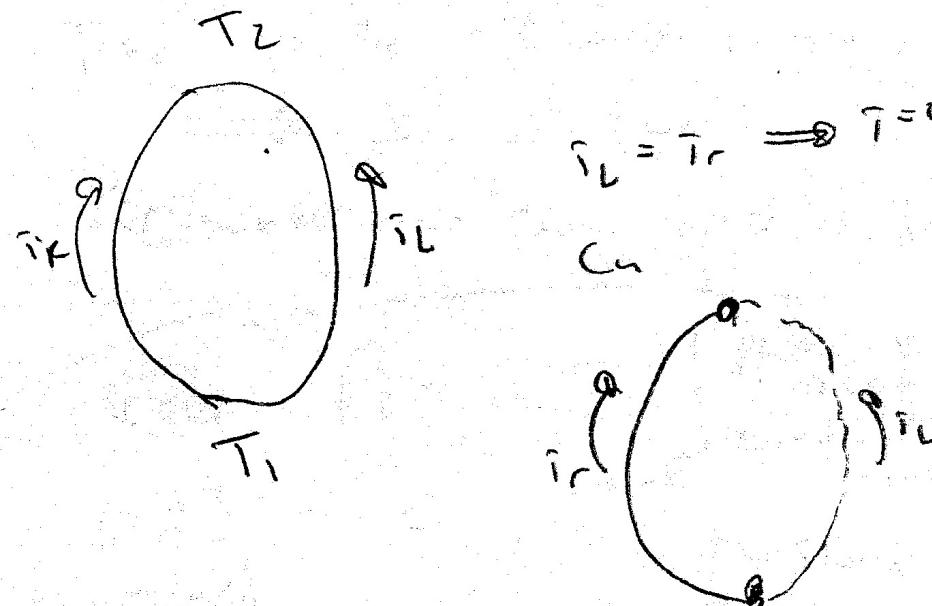
*CargoNet Tag - Singapore to Taiwan - Malinowski M.Eng.*

# Thermocouples

Thomson effect: Thermal gradient sets up an electric field inside conductor

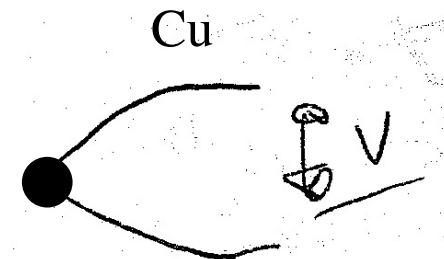
$$\delta V_a = \lambda_a \delta T$$

Seebeck coefficient  
(prop. of material)



$$i_L = i_r \Rightarrow T = 0$$

Thermocouple

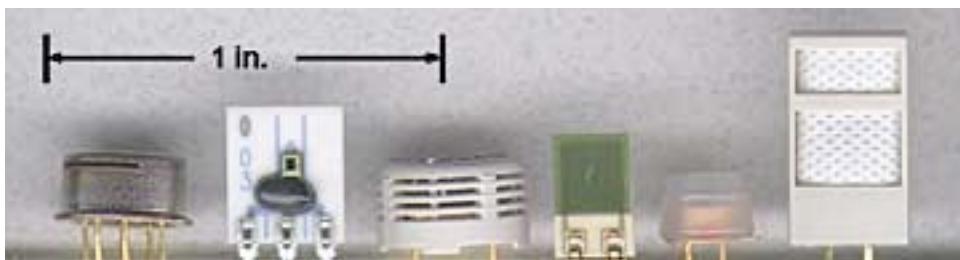


Constatan

$V_{Left} \neq V_{Right}$ ,  $\lambda_a$  different  
 $\Rightarrow i_r \neq i_L \Rightarrow T \neq 0 !!$

[one metal has to give up electrons  
at  $T_2 - T_1$  more than the other]

# Humidity Sensors



## Capacitive

The typical uncertainty of capacitive sensors is  $\pm 2\%$  RH from 5% to 95% RH with two-point calibration

## Resistive

Many varieties of capacitive humidity sensors  
Exponential resistance-to-RH characteristic  
Often coat board substrate with polymer.  
Temperature compensation needed.  
Interdigitated fingers - need AC source

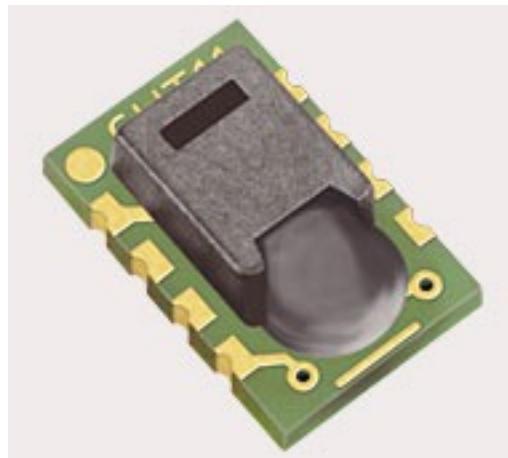
## Thermal

For measuring absolute humidity at high temperatures, thermal conductivity sensors are often used. They differ in operating principle from resistive and capacitive sensors. Absolute humidity sensors are left and center; thermistor chambers are on the right.

*Other types: Chilled Mirror optical humidity sensor, etc.*

<http://www.sensorsmag.com/sensors/article/articleDetail.jsp?id=322590>

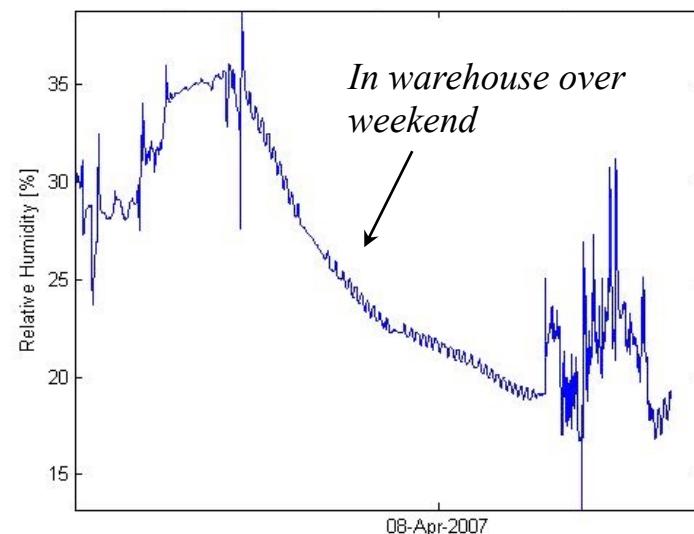
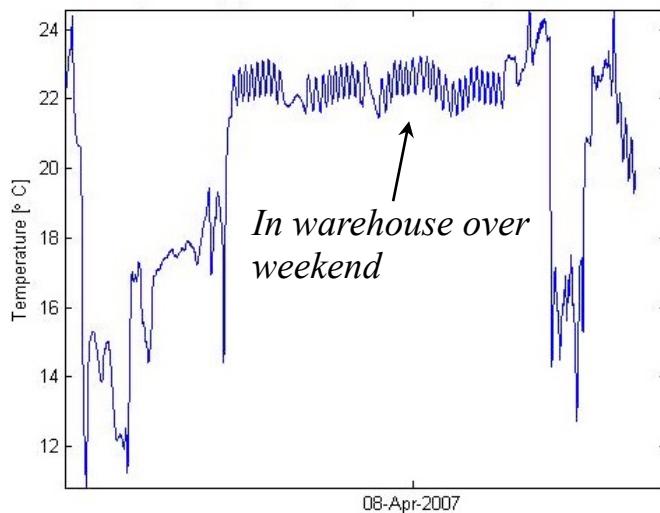
# “Inexpensive” Surface-Mount Humidity Sensor Sensirion SHT11



2 sensors for relative humidity & temperature  
Precise dewpoint calculation possible  
Measurement range: 0-100% RH  
Absolute RH accuracy: +/- 3% RH  
Temp. accuracy: +/- 0.4° C @ 25 ° C  
Calibrated & digital output (2-wire interface)  
Fast response time < 4 sec.  
Low power consumption (typ. 30 µW)

5 day test:

- Ship to Pepsi
- Weekend in warehouse
- On delivery truck
- Ship back to MIT

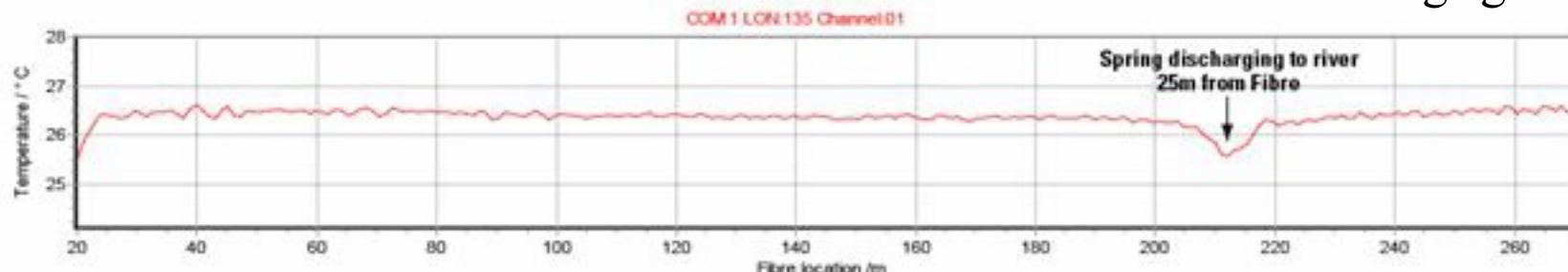


- Surface mount - precise temperature & humidity measured
- Digital connection - readings are compensated

# Fiber Optic Temperature Sensors

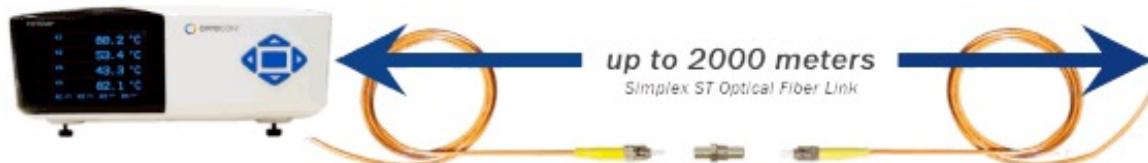
300m FIBRE TRACE 30/182 8/10/2006 12:39:18

[water.usgs.gov](http://water.usgs.gov)



**FOTEMP Series**  
*Single & Multichannel Interfaces*  
RS232, RS485, USB and Profibus DP

**TS Series**  
*Temperature Probes*  
-200°C to +300°C



[www.micronor.com](http://www.micronor.com)

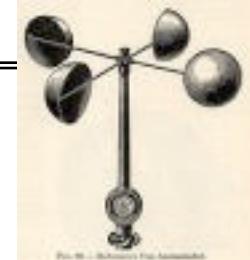
- Temperature affects index of refraction (hence reflected/transmitted signal) across fiber
- Use Time-Domain Reflectometry to get circa 1 meter T resolution across km's of optical fiber

# Anemometer

Rotating cups...

Fan blades

On shaft encoder



- Measures wind speed
  - Heat source and temperature sensors exposed to airflow (Hot Wire Anemometer)

$$\bullet \Delta Q \rightarrow \Delta T$$

• Use Thermistors, Transistors, Tungsten Bulb!

*Can do it all on a silicon chip!*



- Ultrasonic Anemometers

– Measure the change in velocity with wind

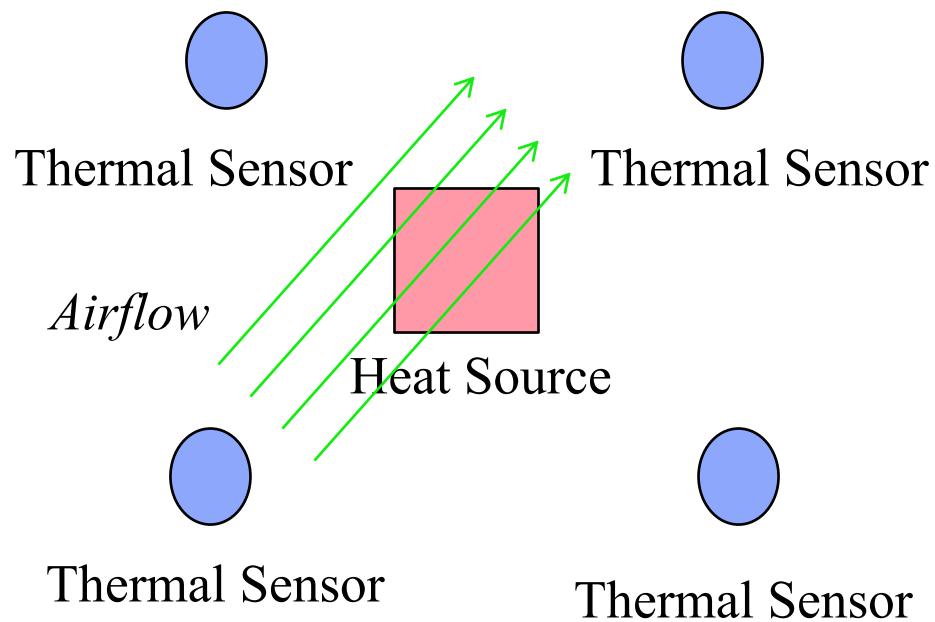
- Can break into components

$$t = D/(c \pm v)$$

*Sonic propagation time = distance over (soundspeed  $\pm$  wind velocity)*

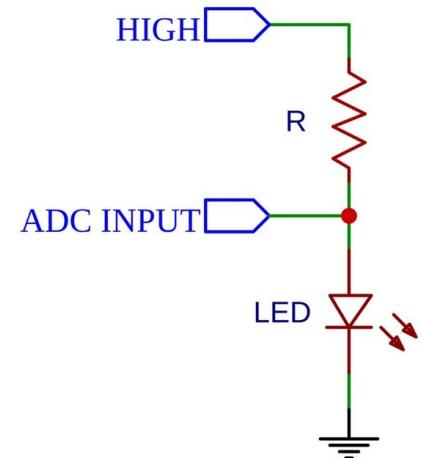
- Microphone in tube, bendy sensor, accel. or piezo blowing in wind, etc...

# Planar Thermal Anemometer



Like a MEMSIC accelerometer with the cover off

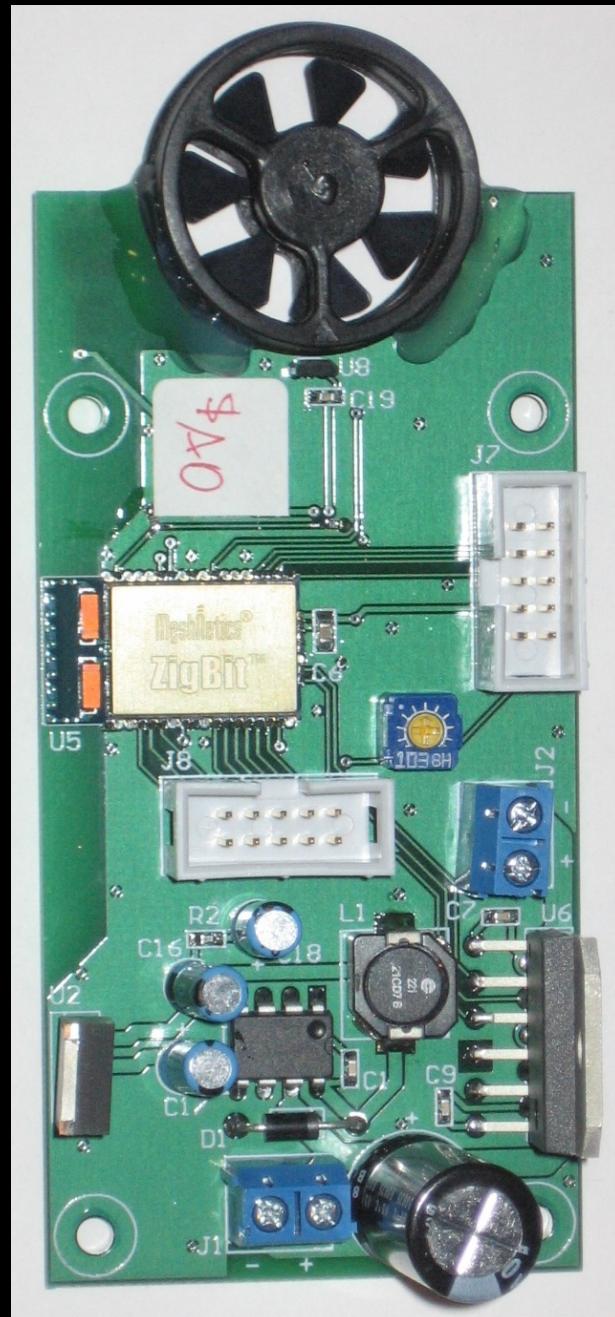
# Paul Dietz's LED Anemometer



[https://youtu.be/TD6A\\_tvbKT0](https://youtu.be/TD6A_tvbKT0)

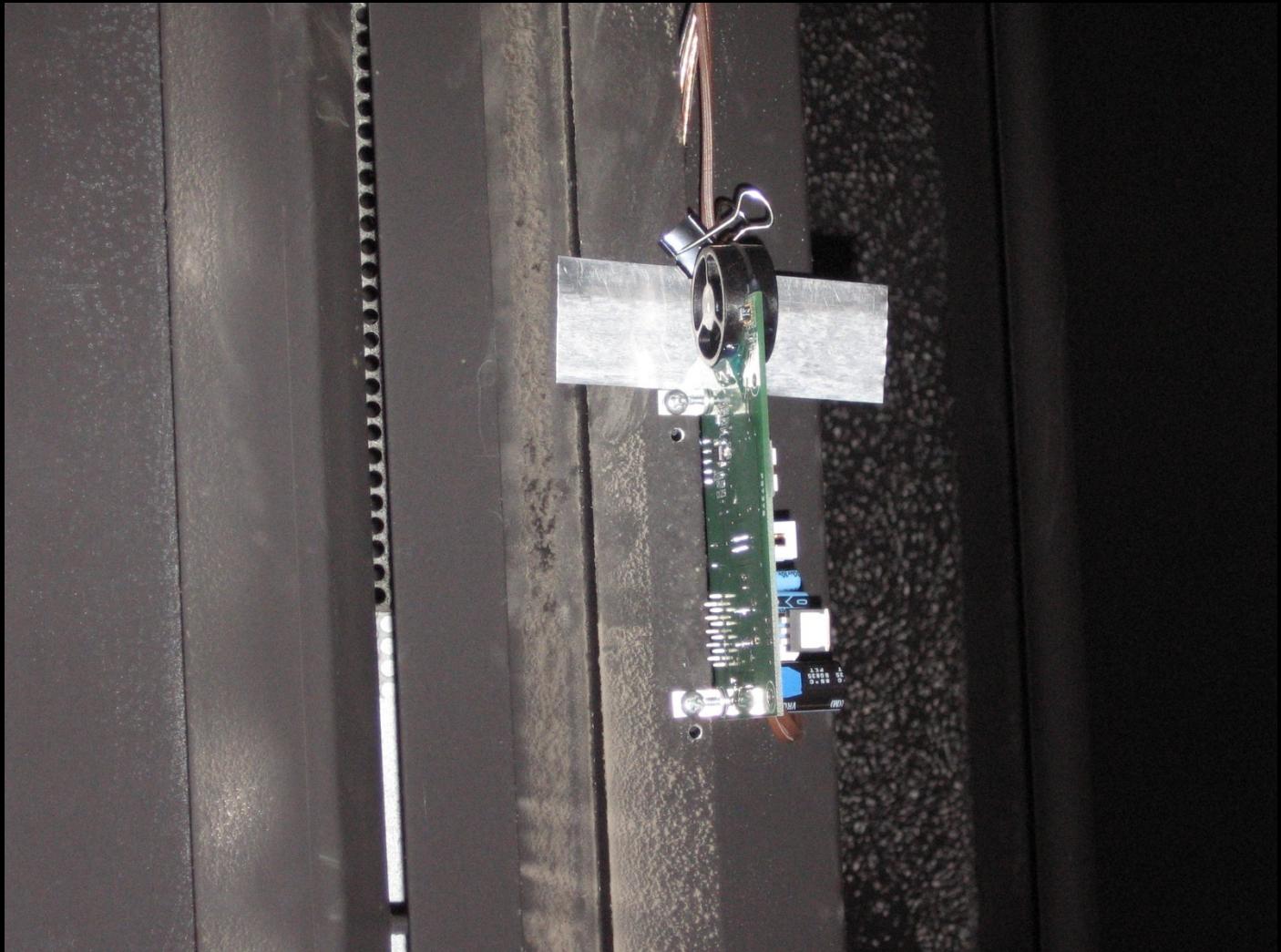
# CONTROL NODE

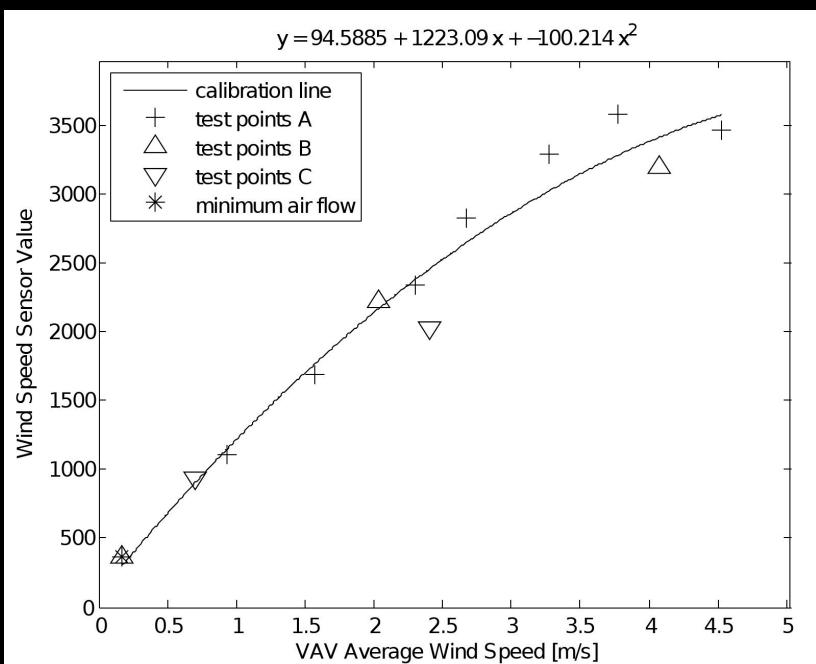
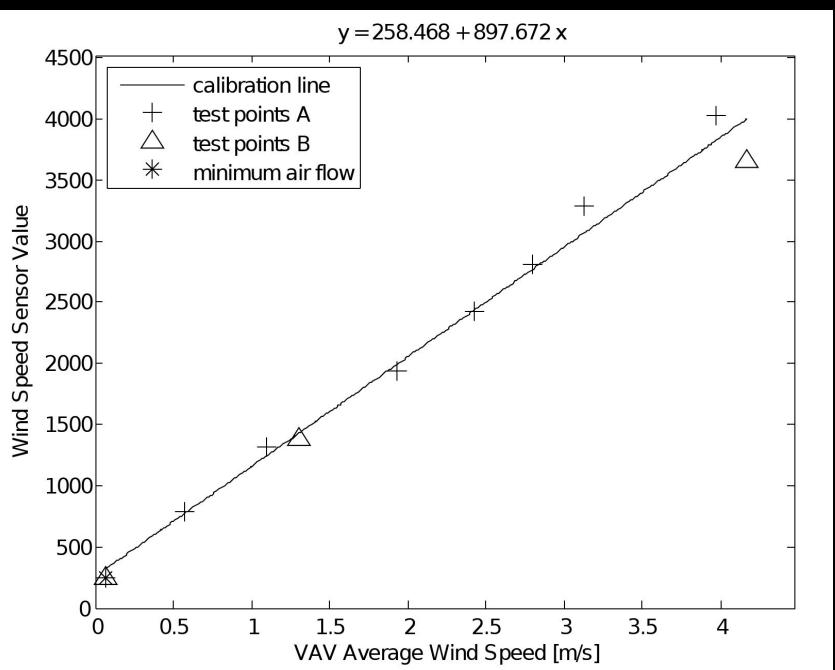
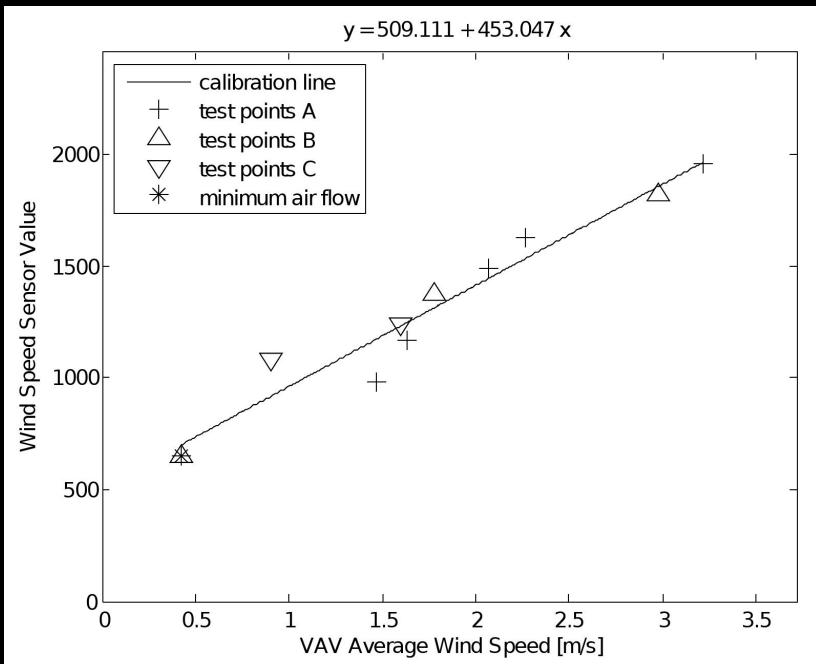
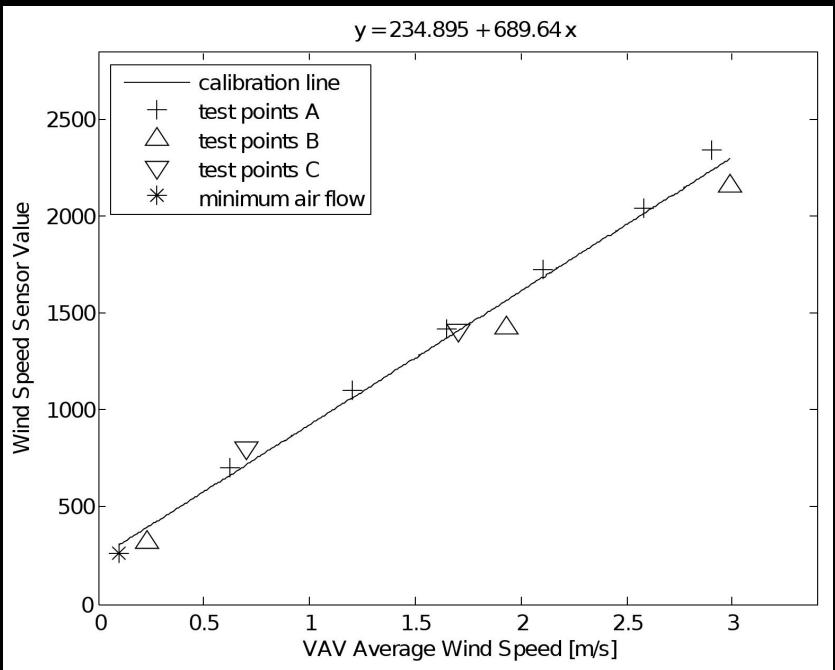
- Wind speed sensor
- Temperature sensor
- Humidity sensor
- Light sensor
- Motor driver
- Wireless transceiver
- 8MHz microcontroller
- 24Vdc power supply
- Expansion port

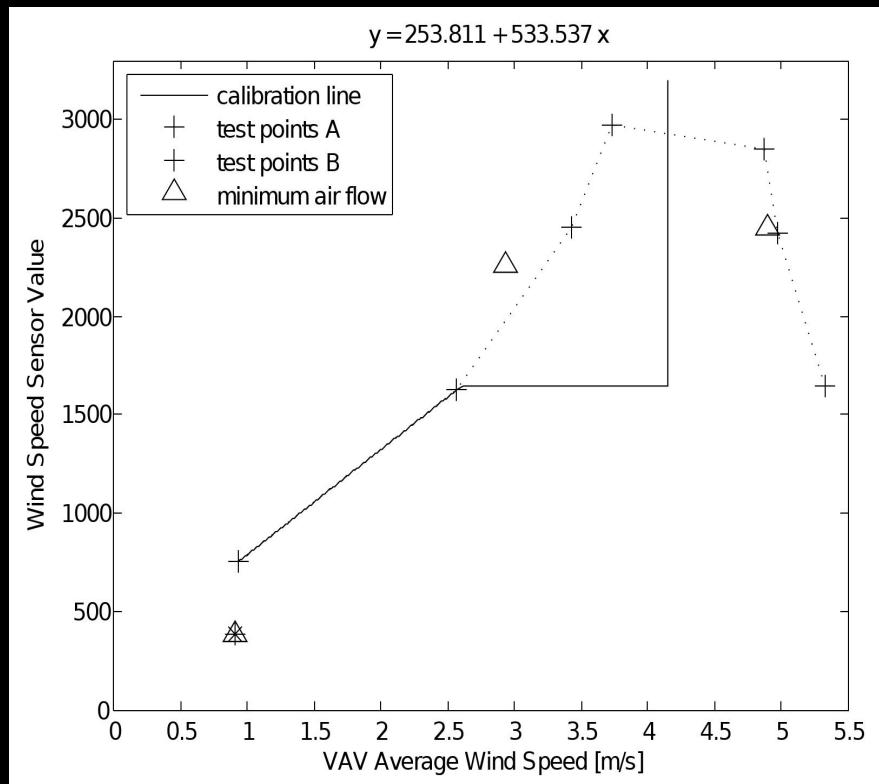
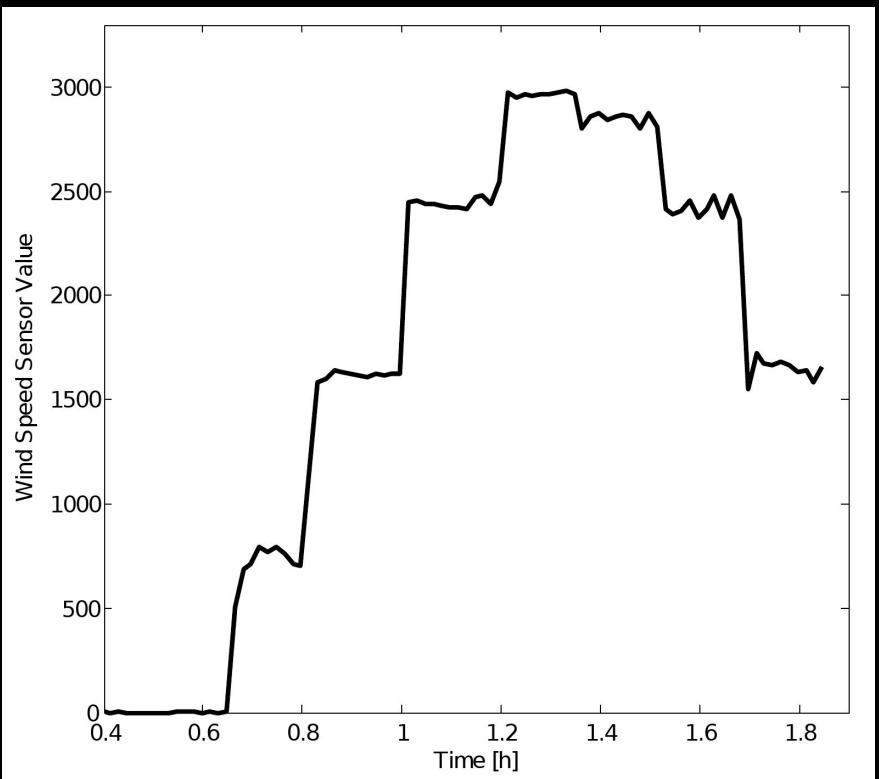


# WIND SPEED SENSOR

- Noise
- Sensitivity
- Calibration
- Energy
- metrics

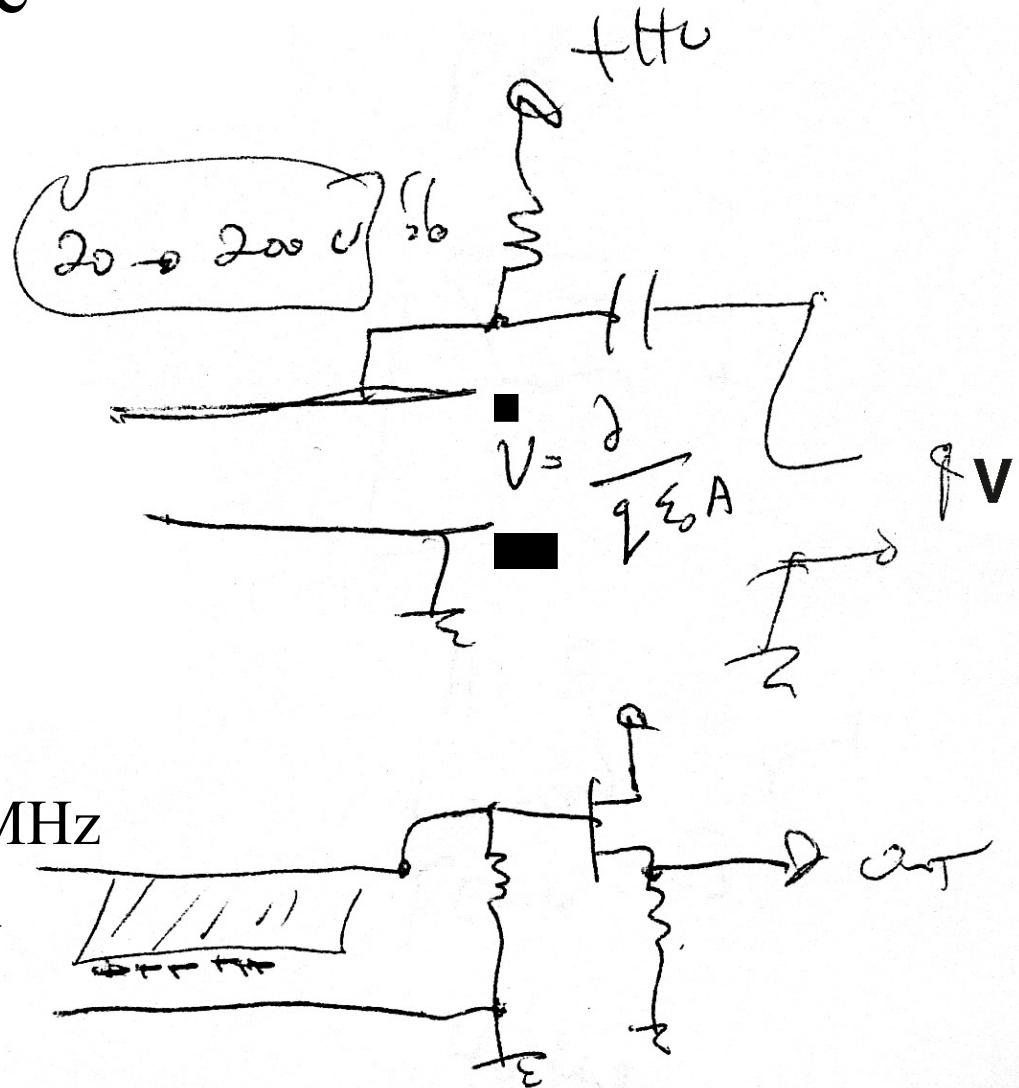






# Acoustic Transducers

- Measure dynamic range to moving diaphragm
- Carbon mic
- Condensor mic
- Electret mic
  - Foil electret mic
  - FEP material polarized with corona discharge
  - Wideband
    - $10^{-3}$  Hz to hundreds of MHz
  - Usually have integrated FET



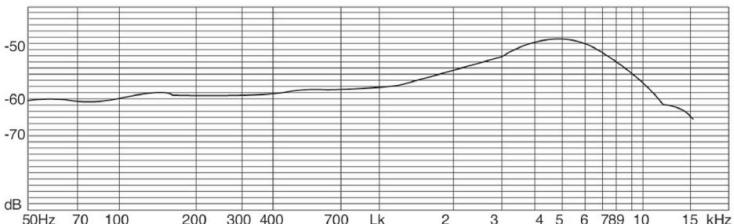
# More Acoustic Transducers



→ Preso Mic

~ Peaty (Passive Acoustic Filters)?

⇒ PZT



PVDF

Diaphragm

⇒ Electrodynamic mic ~ many coil

→ Speaker  
or  
mic

⇒ dB re.  $1 \mu\text{Pa}$

⇒ Optical techniques  
(SPOT Scans)

# PZT Cellphone Receiver

Terminal:  
RXMODELS48

Serial No:  
RXMODELS48

Transducer:  
WM70

Unit#: None

Operator: AV

95-08-28

Rec#:  
SCRATCH  
1

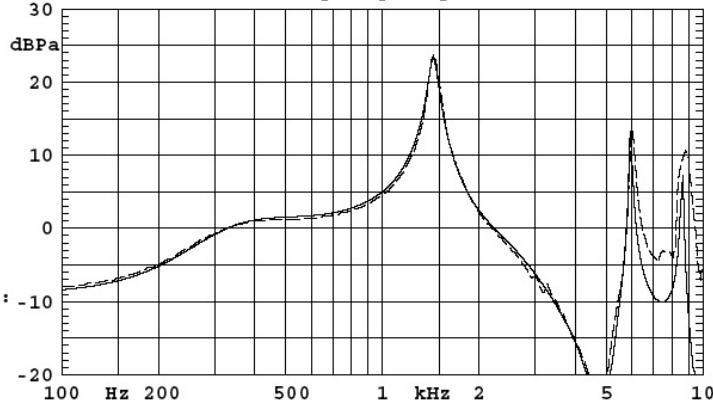
1 kHz value:  
5.0 dBPa

Drive Voltage: -10  
.000 Vrms

V-angle: 0  
H-angle: 0

Lev(OLR-Avg): -20  
4.4 dBPa

Frequency Response



— Computer Prediction  
- - - Measurement (Rec#:RXMODELS48)

- Acoustic response of piezo element and substrate alone
- Sealed to artificial ear

Just PZT plate

Terminal:  
RXMODELS48

Serial No:  
RXMODELS48

Transducer:  
WM70

Unit#: None

Operator: AV

95-08-28

Rec#:  
SCRATCH  
1

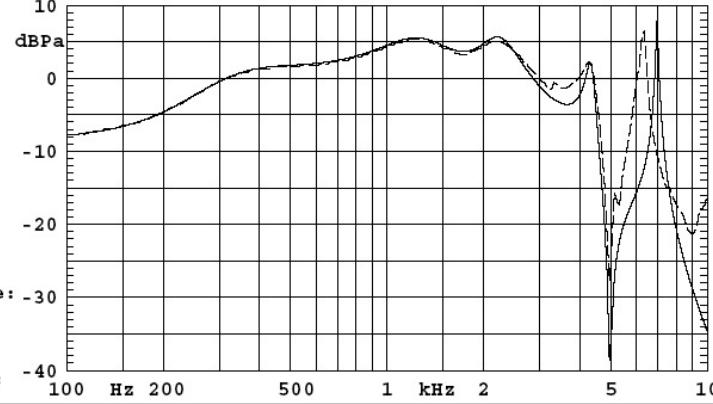
1 kHz value:  
4.5 dBPa

Drive Voltage: -30  
.000 Vrms

V-angle: 0  
H-angle: 0

Lev(OLR-Avg): -40  
2.9 dBPa

Frequency Response



— Computer Prediction  
- - - Measurement (Rec#:RXMODELS45)

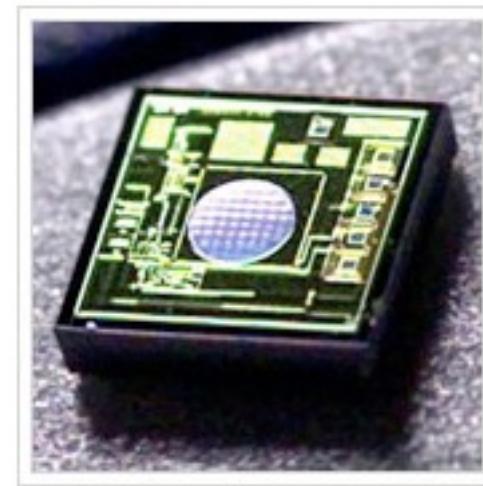
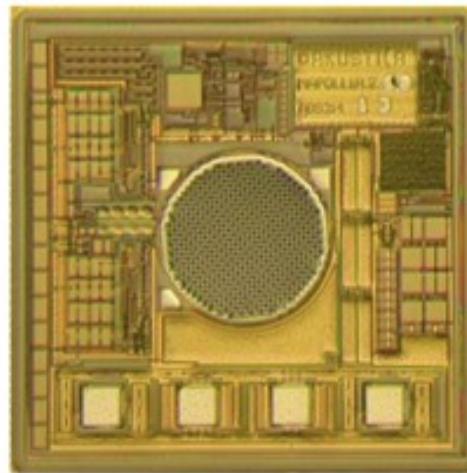
- Acoustic response of piezo receiver
- Sealed to artificial ear

After mechanical compensation in receiver

*Nortel Measurements*

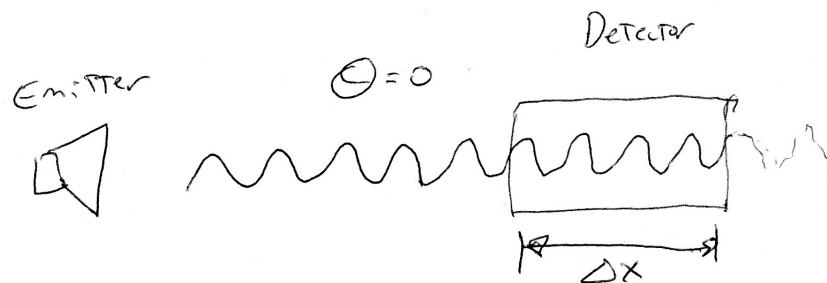
# MEMs Microphones

The World's Smallest Microphone!



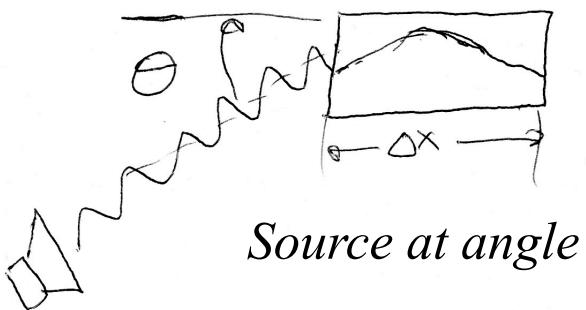
- Many Manufacturers
  - Akustica (direct digital output), Infineon, Panasonic, etc.
- Very small - surface-mount chip
- Have integrated amplifier and sometimes ADC

# Where Beamwidth Comes From



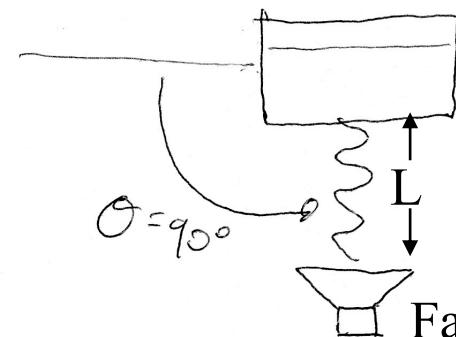
$$\int_{\Delta x} V_{T_N} dx = V(T)|_n \Rightarrow 0$$

*Source on edge*



$$\int_{\Delta x} V_{T_N} dx = \alpha V(T)_n \Rightarrow \alpha V(T)_n \quad (\alpha < 1)$$

*Source at angle*



$$\int_{\Delta x} V_{T_N} dx = V(T)_n$$

(In far field,  
Waveform at  $T_N$   
is constant across  
aperture  $\Delta x$ )

*Source broadside*  
Far-field ( $L \gg \Delta x$ )

# Beamwidth as Fourier Transform

$$V(T) = G \int_{x=-\infty}^{x=+\infty} A(x) \cdot \sin(\omega T + Kx) dx$$

Gain       $x = -\infty$   
 $\nearrow$        $\nwarrow$   
 Aperture  
 Shading  
 function  
 (shape)

$\uparrow$  Wavenumber  
 $\downarrow$   $\cos(\theta) 2\pi/\lambda$

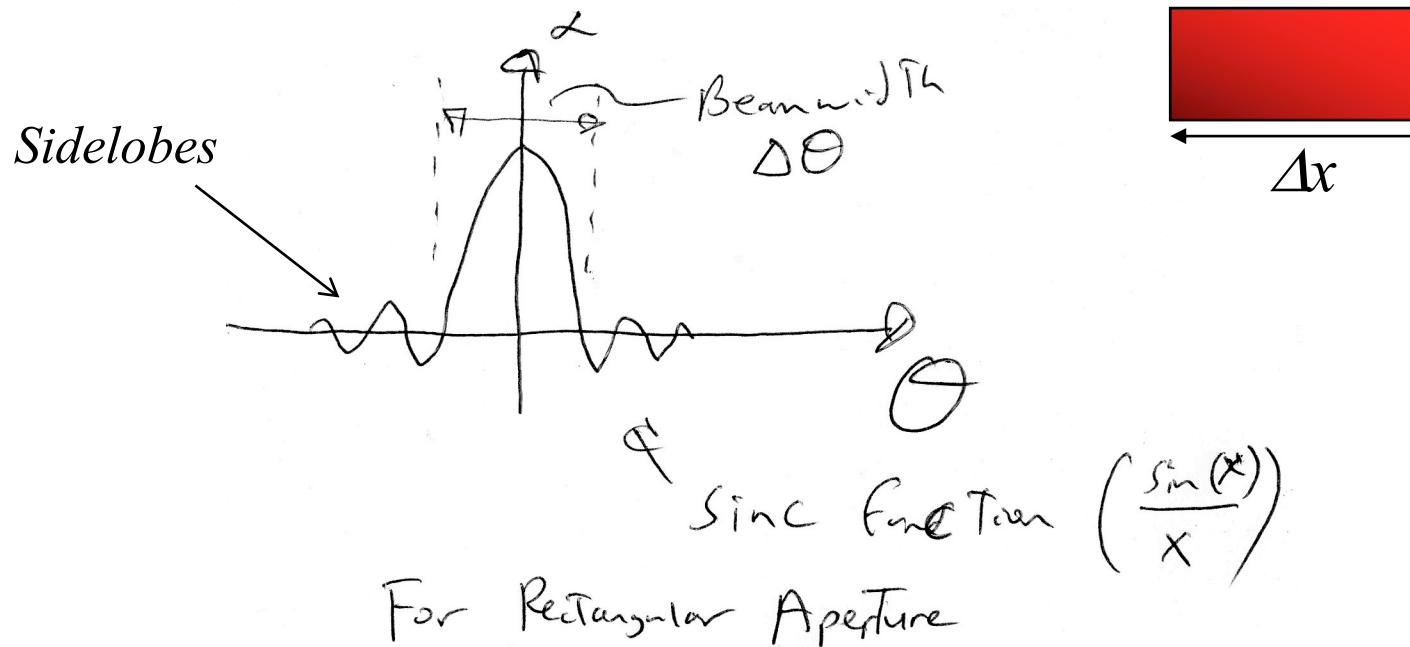
$$V(T) = G e^{i\omega T} \int_{-\Delta x}^{\Delta x} A(x) e^{i \frac{2\pi \cos \theta}{\lambda} x} dx$$

$$|V(x)| \iff |V(\cos \theta)|$$

$\downarrow$   
 Fourier  
 transform

K is the trace wavenumber

# Beamwidth of Rectangular Aperture



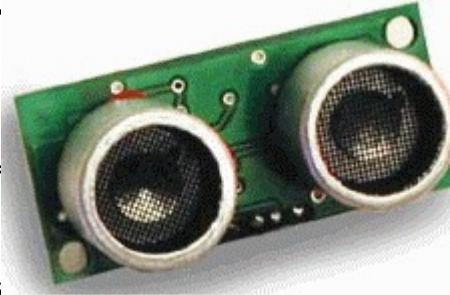
$$\Delta\theta_{3dB} = 50^\circ \quad \lambda/\Delta x$$

$$\lambda \ll \Delta x$$

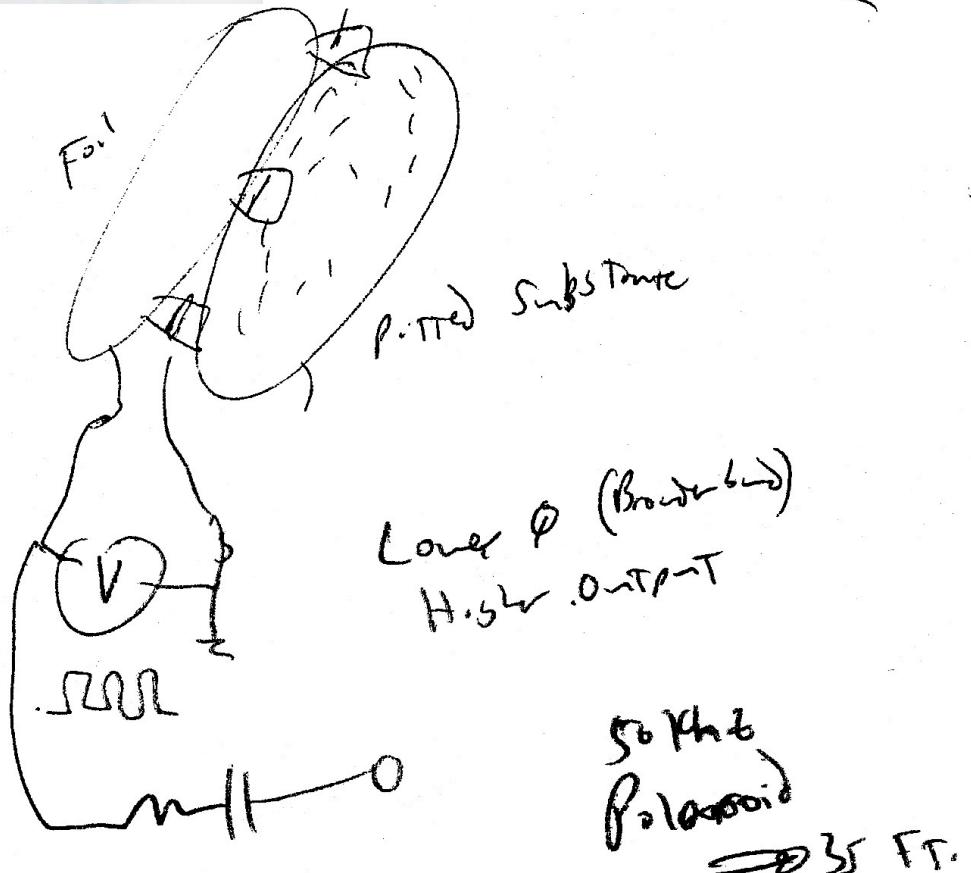
*Beamwidth and aperture width are conjugate variables!*



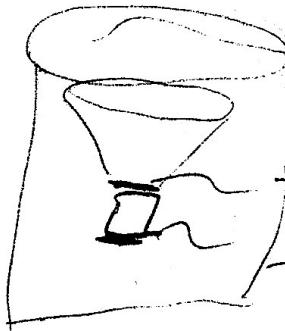
# Ultrasonic Transceivers



Electrostatic



Pc



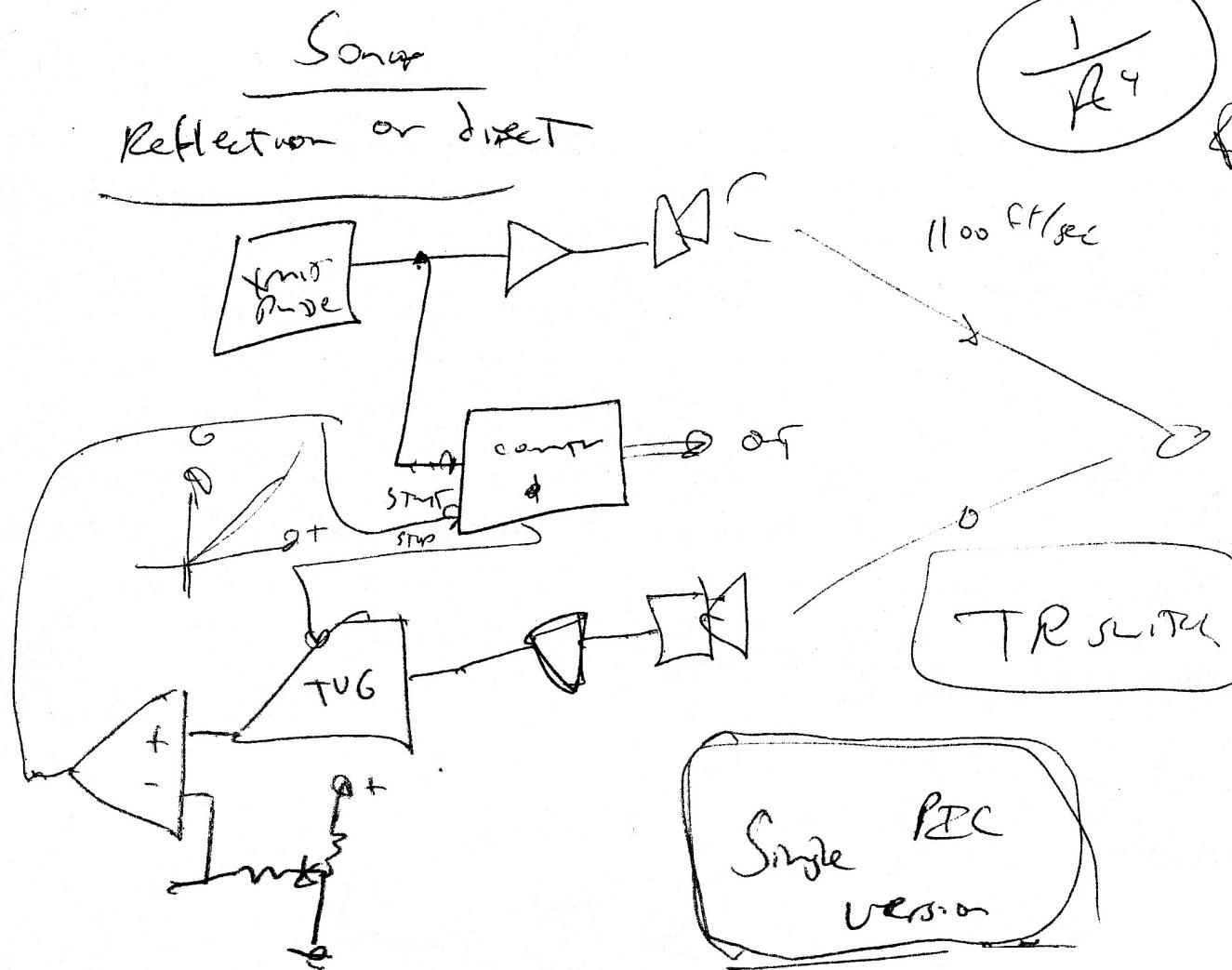
H. φ

Limited output  
[Except...]

40 kHz

Piezoelectric, mostly PZT

# Sonar

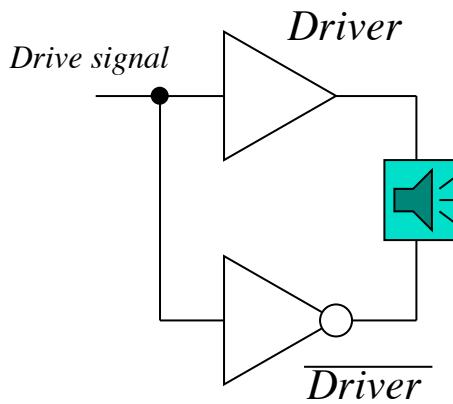


$$K_r T_0 e^{-2\pi R} = I_r$$

$$\frac{1}{16\pi^2 R^4} \text{ Radar Eq:}$$

RC exponential threshold

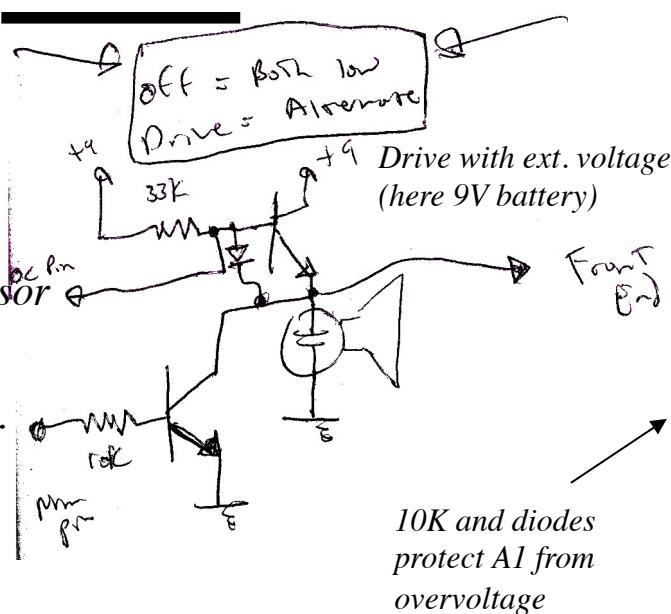
# Sonar with Totem-Pole Driver and Diode-Based T/R Switch



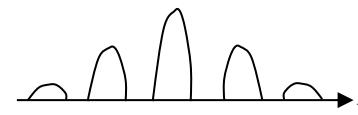
*Complementary drive gives twice the drive voltage vs. driving single-ended to ground*

Sonar Head

Open Collector Pin from Processor



As A1 is not biased up, its output is half-wave rectified (e.g., we only see positive cycles) - this can lead to full-cycle jumps in timing.

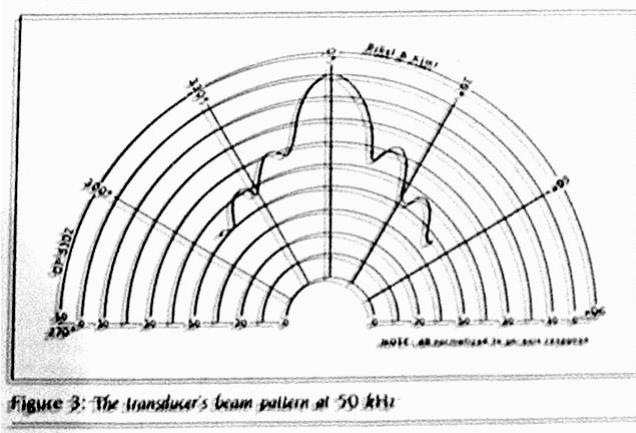
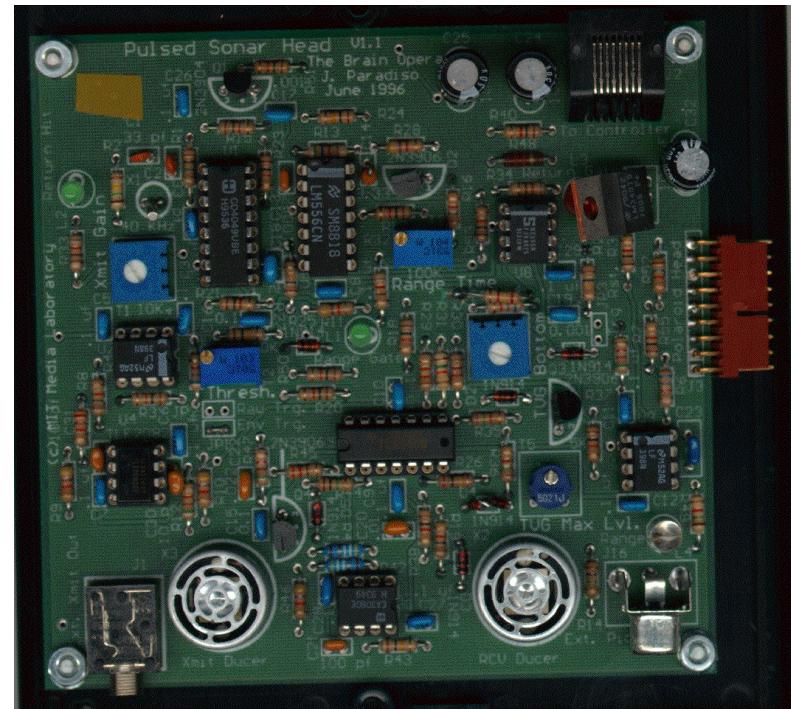
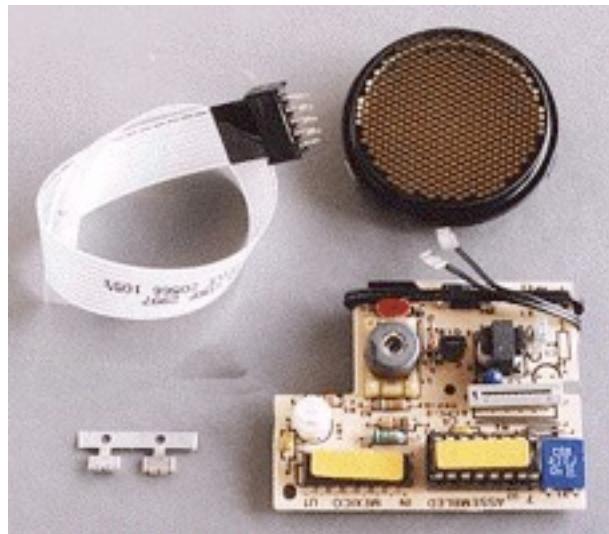


A1

A2

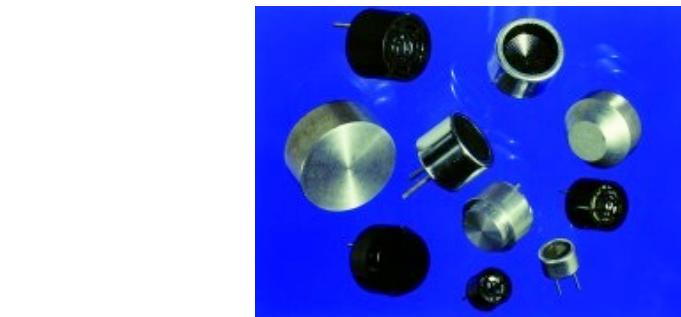
- To drive sonar, the two pins from the processor are driven in opposite polarity (complementary)
- To listen to sonar, both pins are held low
- Both pins positive is a forbidden state (prohibited by the diode between the transistors)

# Sonar Photos...



50 kHz, narrow beamwidth, clicks!

*Polaroid electrostatic*



Generally 40 kHz, 40° - 80° beam, quite

*Piezoceramic (Murata, Panasonic, APC)*

1997

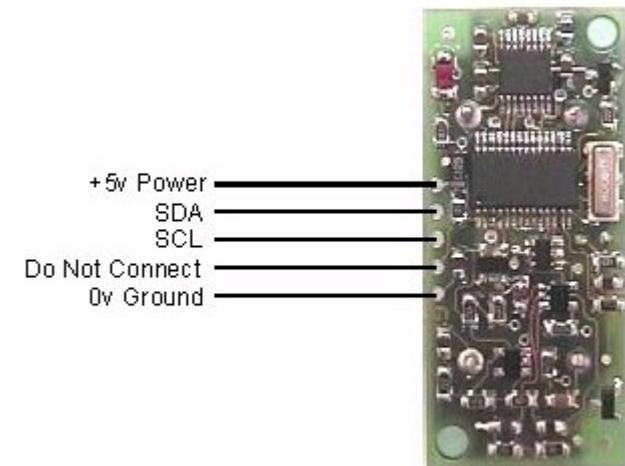
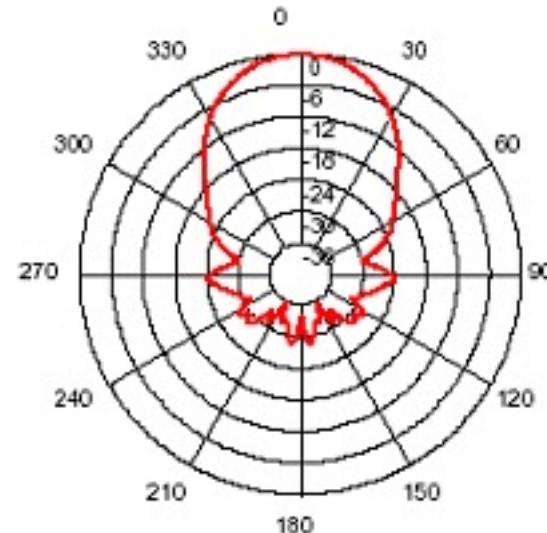




# More 1997



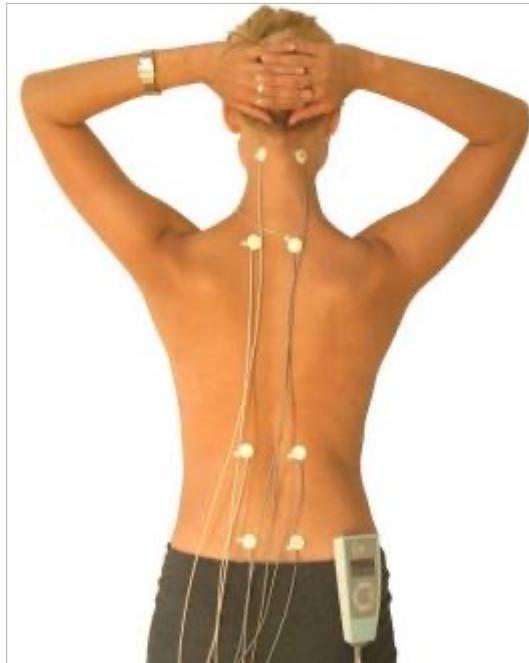
# The SRF08



- Available off robotics sites
- Minimal components – uses dual PZT ‘ducers
- Uses TVG
- Claims Range of 6 meters
- Onboard processor – talks via I<sup>2</sup>C

# sonoSens® Monitor

## Mobile Motion Analysis



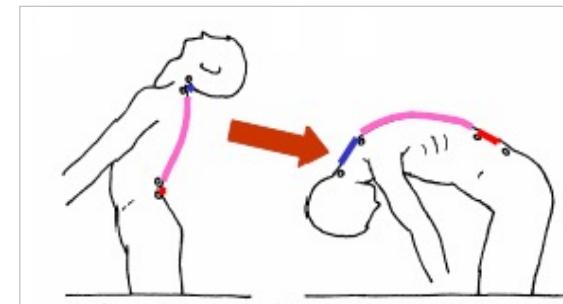
*Application of sensors along the spine.*

Because of the small sensor size and the light weight of the device (150 g), free motion is possible. Additionally there are no location restrictions; outdoor measurements are therefore possible.

*Launch ultrasound into skin - measure distributed delay times*

**Body movements can be assessed using sonometry.**

The sonoSens® Monitor captures body motion by measuring distance changes between sensors attached to the skin (spine, knee, shoulder, hip, etc.). Sensor movement is caused by the elasticity of the skin – the skin over joints stretches and relaxes according to joint motion. Data is stored in the main unit of the device and transferred to the PC after recording. Maximum measurement time is up to 60 hours.



Sensor movement is caused by the elasticity of the skin.

Videos:  
*Seat  
Breathing*